LM4250 Programmable Operational Amplifier



Literature Number: SNOSC17A

August 2000



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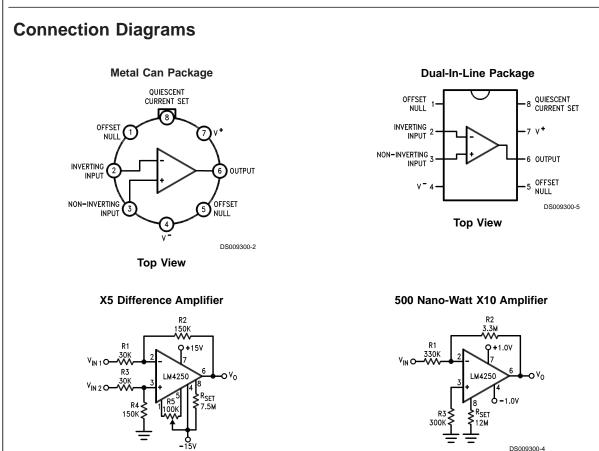
General Description

The LM4250 and LM4250C are extremely versatile programmable monolithic operational amplifiers. A single external master bias current setting resistor programs the input bias current, input offset current, quiescent power consumption, slew rate, input noise, and the gain-bandwidth product. The device is a truly general purpose operational amplifier.

The LM4250C is identical to the LM4250 except that the LM4250C has its performance guaranteed over a 0°C to +70°C temperature range instead of the -55°C to +125°C temperature range of the LM4250.

Features

- ±1V to ±18V power supply operation
- 3 nA input offset current
- Standby power consumption as low as 500 nW
- No frequency compensation required
- Programmable electrical characteristics
- Offset voltage nulling capability
- Can be powered by two flashlight batteries
- Short circuit protection



DS009300-3

Quiescent P_D = 500 nW

Quiescent $P_D = 0.6 \text{ mW}$

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 3)

	LM4250	LM4250C
Supply Voltage	±18V	±18V
Operating Temp. Range	$-55^{\circ}C \le T_A \le +125^{\circ}C$	$0^{\circ}C \le T_{A} \le +70^{\circ}C$
Differential Input Voltage	±30V	±30V
Input Voltage (Note 2)	±15V	±15V
I _{SET} Current	150 nA	150 nA
Output Short Circuit Duration	Continuous	Continuous
T _{JMAX}		
H-Package	150°C	100°C
N-Package		100°C
J-Package	150°C	100°C
M-Package		100°C
Power Dissipation at T _A = 25°C		
H-Package (Still Air)	500 mW	300 mW
(400 LF/Min Air Flow)	1200 mW	1200 mW
N-Package		500 mW
J-Package	1000 mW	600 mW
M-Package		350 mW
Thermal Resistance (Typical) θ_{JA}		
H-Package (Still Air)	165°C/W	165°C/W
(400 LF/Min Air Flow)	65°C/W	65°C/W
N-Package		130°C/W
J-Package	108°C/W	108°C/W
M-Package		190°C/W
(Typical) θ _{JC}		
H-Package	21°C/W	21°C/W
Storage Temperature Range	−65°C to +150°C	−65°C to +150°C
Soldering Information		
Dual-In-Line Package		
Soldering (10 seconds)	260°C	
Small Outline Package		
Vapor Phase (60 seconds)	215°C	
Infrared (15 seconds)	220°C	
See AN-450 "Surface Mounting Methods on Product Reliability" for other methods surface mount devices.		
ESD tolerance (Note 4)	800V	
Note 1: "Absolute Maximum Ratings" indicate limits to the device may occur. Operating Ratings indicate of device is functional, but do not guarantee specific pe	conditions for which the	
Note 2: For supply voltages less than \pm 15V, the all voltage is equal to the supply voltage.		
Note 3: Refer to RETS4250X for military specification	ons.	

Resistor Biasing Set Current Setting Resistor to V⁻

I _{SET}					
Vs	0.1 µA	0.5 μA	1.0 µA	5 µA	10 µA
±1.5V	25.6 MΩ	5.04 MΩ	2.5 MΩ	492 kΩ	244 kΩ
±3.0V	55.6 MΩ	11.0 MΩ	5.5 MΩ	1.09 MΩ	544 kΩ
±6.0V	116 MΩ	23.0 MΩ	11.5 MΩ	2.29 MΩ	1.14 MΩ
±9.0V	176 MΩ	35.0 MΩ	17.5 MΩ	3.49 MΩ	1.74 MΩ
±12.0V	236 MΩ	47.0 MΩ	23.5 MΩ	4.69 MΩ	2.34 MΩ
±15.0V	296 MΩ	59.0 MΩ	29.5 MΩ	5.89 MΩ	2.94 MΩ

Electrical Characteristics

LM4250 (–55°C \leq T_{A} \leq +125°C unless otherwise specified.) T_{A} = T_{J}

		V _s = ±1.5V			
Parameter	Conditions	Ι _{SET} = 1 μΑ		I _{SET} = 10 μA	
		Min	Max	Min	Max
V _{os}	$R_{S} \le 100 \text{ k}\Omega, T_{A} = 25^{\circ}C$		3 mV		5 mV
I _{OS}	$T_A = 25^{\circ}C$		3 nA		10 nA
I _{bias}	$T_A = 25^{\circ}C$		7.5 nA		50 nA
Large Signal Voltage	$R_{L} = 100 \text{ k}\Omega, T_{A} = 25^{\circ}\text{C}$	40k			
Gain	$V_{O} = \pm 0.6 V$, $R_{L} = 10 \text{ k}\Omega$			50k	
Supply Current	$T_A = 25^{\circ}C$		7.5 μA		80 µA
Power Consumption	$T_A = 25^{\circ}C$		23 µW		240 µW
V _{OS}	$R_{S} \le 100 \text{ k}\Omega$		4 mV		6 mV
I _{OS}	T _A = +125°C		5 nA		10 nA
	$T_A = -55^{\circ}C$		3 nA		10 nA
l _{bias}			7.5 nA		50 nA
Input Voltage Range		±0.6V		±0.6V	
Large Signal Voltage Gain	$V_{O} = \pm 0.5 V$, $R_{L} = 100 \text{ k}\Omega$	30k			
	$R_L = 10 \ k\Omega$			30k	
Output Voltage Swing	$R_L = 100 \ k\Omega$	±0.6V			
	$R_{L} = 10 \ k\Omega$			±0.6V	
Common Mode Rejection Ratio	$R_{S} \le 10 \text{ k}\Omega$	70 dB		70 dB	
Supply Voltage Rejection Ratio	$R_{S} \le 10 \text{ k}\Omega$	76 dB		76 dB	
Supply Current			8 µA		90 µA

	Conditions	$V_s = \pm 15V$			
Parameter		Ι _{SET} = 1 μΑ		Ι _{SET} = 10 μΑ	
		Min	Max	Min	Max
V _{OS}	$R_{S} \le 100 \text{ k}\Omega, T_{A} = 25^{\circ}C$		3 mV		5 mV
I _{OS}	$T_A = 25^{\circ}C$		3 nA		10 nA
l _{bias}	$T_A = 25^{\circ}C$		7.5 nA		50 nA
Large Signal Voltage	$R_{L} = 100 \text{ k}\Omega, T_{A} = 25^{\circ}\text{C}$	100k			
Gain	$V_{O} = \pm 10V, R_{L} = 10 \text{ k}\Omega$			100k	
Supply Current	$T_A = 25^{\circ}C$		10 µA		90 µA
Power Consumption	$T_A = 25^{\circ}C$		300 µW		2.7 mW
V _{os}	R _S ≤ 100 kΩ		4 mV		6 mV
I _{os}	T _A = +125°C		25 nA		25 nA
	$T_A = -55^{\circ}C$		3 nA		10 nA
I _{bias}			7.5 nA		50 nA
Input Voltage Range		±13.5V		±13.5V	

Electrical Characteristics (Continued)

		V _s = ±15V			
Parameter	Conditions	Ι _{SET} = 1 μΑ		Ι _{SET} = 10 μΑ	
		Min	Max	Min	Max
Large Signal Voltage	$V_{O} = \pm 10V, R_{L} = 100 \text{ k}\Omega$	50k			
Gain	$R_{L} = 10 \ k\Omega$			50k	
Output Voltage Swing	$R_{L} = 100 \text{ k}\Omega$	±12V			
	$R_{L} = 10 \ k\Omega$			±12V	
Common Mode Rejection Ratio	$R_{S} \le 10 \text{ k}\Omega$	70 dB		70 dB	
Supply Voltage Rejection Ratio	$R_{S} \le 10 \text{ k}\Omega$	76 dB		76 dB	
Supply Current			11 µA		100 µA
Power Consumption			330 µW		3 mW

Electrical Characteristics

LM4250C (0°C \leq T_A \leq +70°C unless otherwise specified.) T_A = T_J

		V _s = ±1.5V			
Parameter	Conditions	I _{SET}	= 1 µA	μΑ I _{SET} =	
		Min	Max	Min	Max
V _{os}	$R_{S} \leq 100 \text{ k}\Omega, T_{A} = 25^{\circ}C$		5 mV		6 mV
I _{OS}	$T_A = 25^{\circ}C$		6 nA		20 nA
l _{bias}	$T_A = 25^{\circ}C$		10 nA		75 nA
Large Signal Voltage Gain	$R_{L} = 100 \text{ k}\Omega, T_{A} = 25^{\circ}\text{C}$	25k			
	$V_{O} = \pm 0.6V, R_{L} = 10 \text{ k}\Omega$			25k	
Supply Current	$T_A = 25^{\circ}C$		8 μΑ		90 µA
Power Consumption	$T_A = 25^{\circ}C$		24 µW		270 µW
V _{os}	$R_{S} \le 10 \text{ k}\Omega$		6.5 mV		7.5 mV
I _{os}			8 nA		25 nA
bias			10 nA		80 nA
Input Voltage Range		±0.6V		±0.6V	
Large Signal Voltage	$V_{O} = \pm 0.5 V, R_{L} = 100 \text{ k}\Omega$	25k			
Gain	$R_{L} = 10 \ k\Omega$			25k	
Output Voltage Swing	$R_L = 100 \text{ k}\Omega$	±0.6V			
	$R_{L} = 10 \ k\Omega$			±0.6V	
Common Mode Rejection Ratio	$R_{S} \le 10 \text{ k}\Omega$	70 dB		70 dB	
Supply Voltage Rejection Ratio	$R_{s} \le 10 \text{ k}\Omega$	74 dB		74 dB	
Supply Current			8 μΑ		90 µA
Power Consumption			24 µW		270 µW
			V _s = :	±15V	
Parameter	Conditions	I _{SET} :	= 1 µA	I _{SET} =	= 10 µA
		Min	Max	Min	Max
V _{OS}	$R_{S} \leq 100 \text{ k}\Omega, T_{A} = 25^{\circ}C$		5 mV		6 mV
I _{os}	$T_A = 25^{\circ}C$		6 nA		20 nA
I _{bias}	$T_A = 25^{\circ}C$		10 nA		75 nA
Large Signal Voltage	$R_{L} = 100 \text{ k}\Omega, T_{A} = 25^{\circ}\text{C}$	60k			
Gain	$V_{O} = \pm 10V, R_{L} = 10 \text{ k}\Omega$			60k	
Supply Current	$T_A = 25^{\circ}C$		11 µA		100 µA
Power Consumption	$T_A = 25^{\circ}C$		330 µW		3 mW
V _{OS}	$R_{S} \le 100 \text{ k}\Omega$		6.5 mV		7.5 mV
					1

 I_{OS}

 $I_{\rm bias}$

8 nA

10 nA

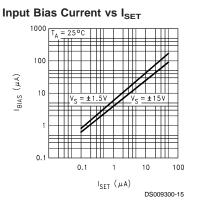
25 nA

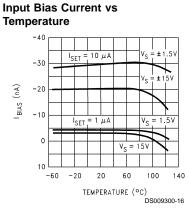
80 nA

Electrical Characteristics (Continued)

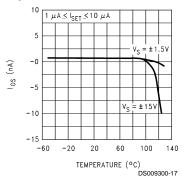
		$V_s = \pm 15V$			
Parameter	Conditions	Ι _{SET} = 1 μΑ		I _{SET} = 10 μA	
		Min	Max	Min	Max
Input Voltage Range		±13.5V		±13.5V	
Large Signal Voltage	$V_{O} = \pm 10V, R_{L} = 100 \text{ k}\Omega$	50k			
Gain	$R_{L} = 10 \ k\Omega$			50k	
Output Voltage Swing	R _L = 100 kΩ	±12V			
	$R_{L} = 10 \ k\Omega$			±12V	
Common Mode Rejection Ratio	$R_{S} \le 10 \text{ k}\Omega$	70 dB		70 dB	
Supply Voltage Rejection Ratio	$R_{S} \le 10 \text{ k}\Omega$	74 dB		74 dB	
Supply Current			11 µA		100 µ/
Power Consumption			330 µW		3 mW

Typical Performance Characteristics

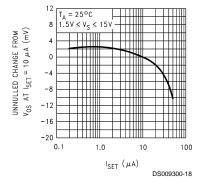




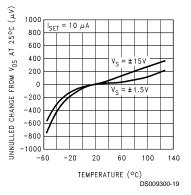
Input Offset Current vs Temperature



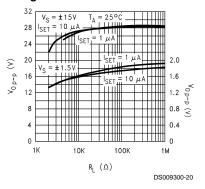
Unnulled Input Offset Voltage Change vs ${\rm I}_{\rm SET}$

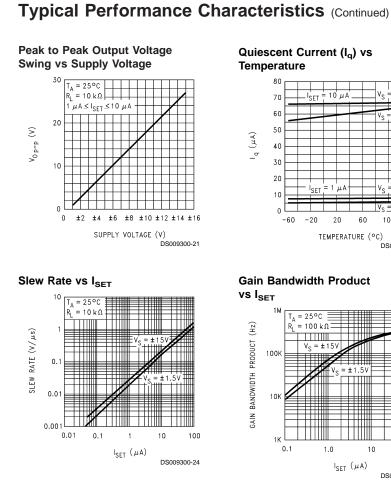


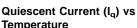
Unnulled Input Offset Voltage Change vs Temperature

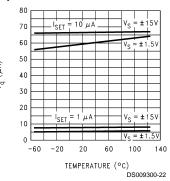


Peak to Peak Output Voltage Swing vs Load Resistance

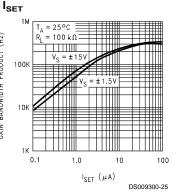




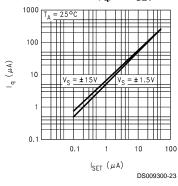




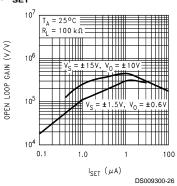
Gain Bandwidth Product



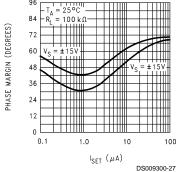
Quiescent Current (Iq) vs ISET



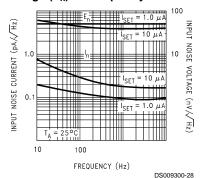
Open Loop Voltage Gain vs I_{SET}



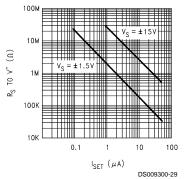
Phase Margin vs I_{SET} 96



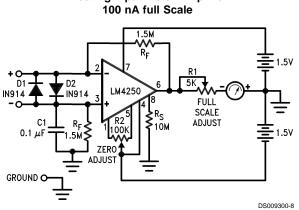
Input Noise Current (In) and Voltage (E_n) vs Frequency



R_{SET} vs I_{SET}

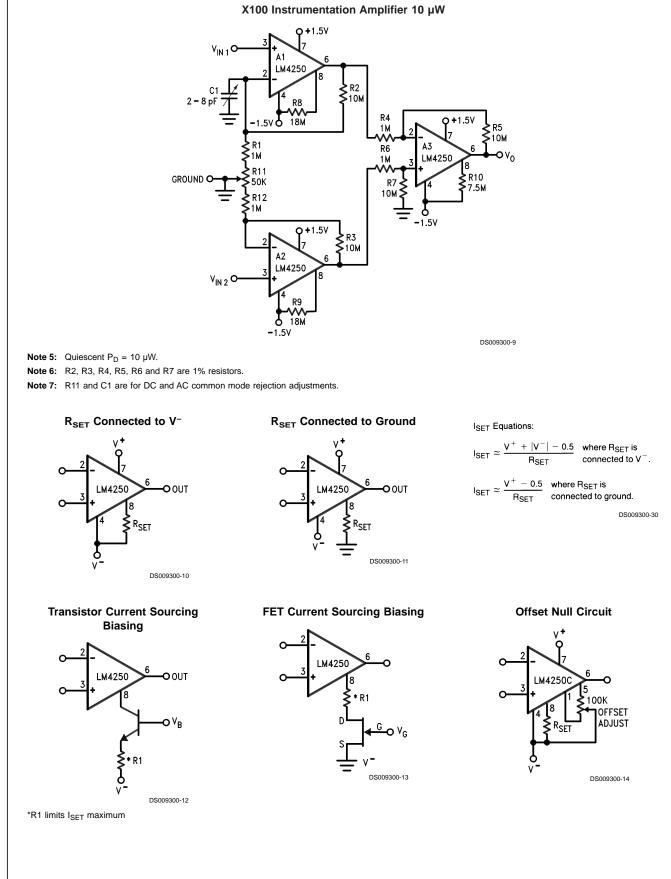


Typical Applications X5 Difference Amplifier 500 Nano-Watt X10 Amplifier R2 3.3M R2 150K R1 R1 **Q+**15V **Q+**1.0V 330K 30k VIN 10 VINO R3 6 LM4250 **۰**۷₀ LM4250 ۷'n 30K 8 V_{IN 2} O-R_{SET} Q **-**1.0V R5 R4 7.5M 100k 150K R3 RSET 300ŀ 2M DS009300-4 DS009300-3 Quiescent $P_D = 500 \text{ nW}$ Quiescent $P_D = 0.6 \text{ mW}$ **Floating Input Meter Amplifier**

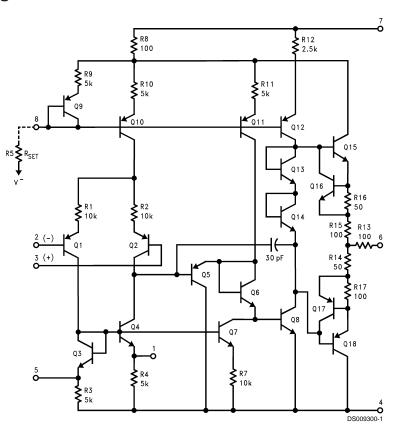


Quiescent P_D = 1.8 μW *Meter movement (0–100 $\mu A,$ 2 k $\Omega)$ marked for 0–100 nA full scale.

Typical Applications (Continued)



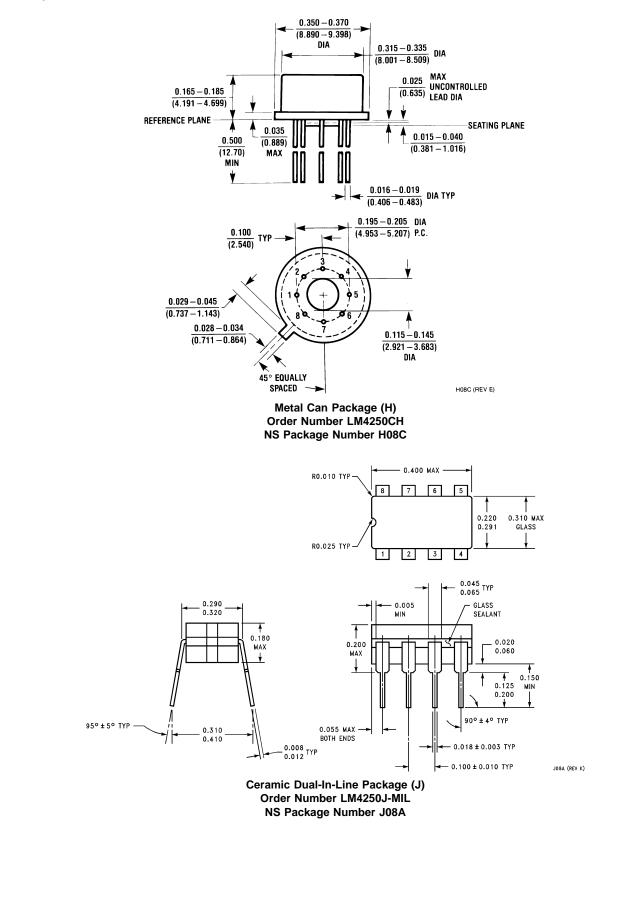
Schematic Diagram

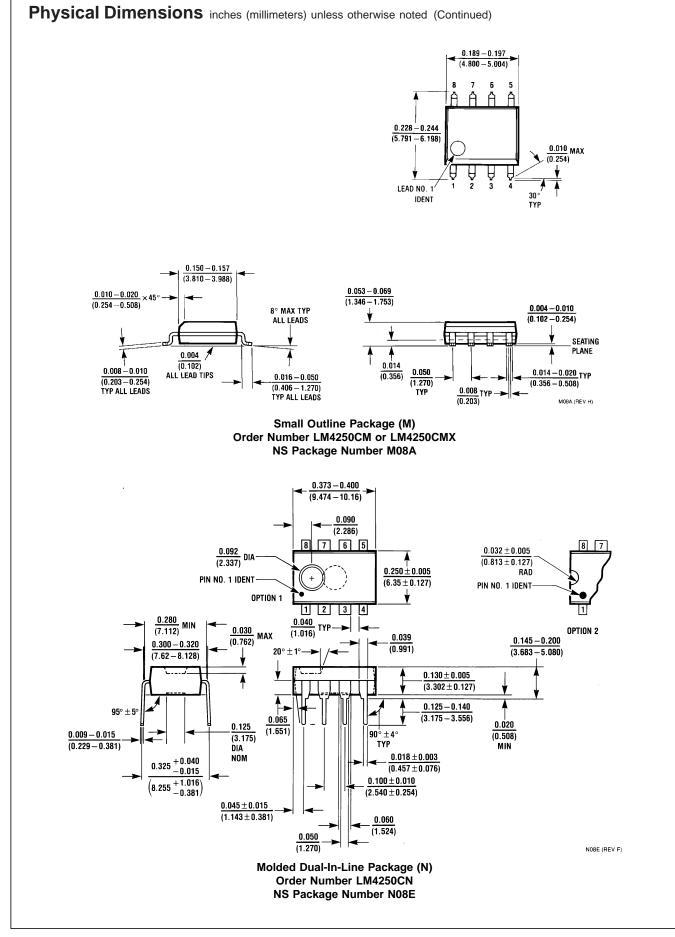


Ordering Information

Temperature Range		Package	NSC
Military	Commercial		Package
$\textbf{-55^{\circ}C} \leq \textbf{T}_{\textbf{A}} \leq \textbf{+125^{\circ}C}$	$0^{\circ}\mathbf{C} \leq \mathbf{T}_{\mathbf{A}} \leq \mathbf{+70}^{\circ}\mathbf{C}$		Number
	LM4250CN	8-Pin	N08E
		Molded DIP	
	LM4250CM	8-Pin	M08A
	LM4250CMX	Surface Mount	
		8-Pin	J08E
LM4250J-MIL		Ceramic DIP	
	LM4250CH	8-Pin	H08C
		Metal Can	







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